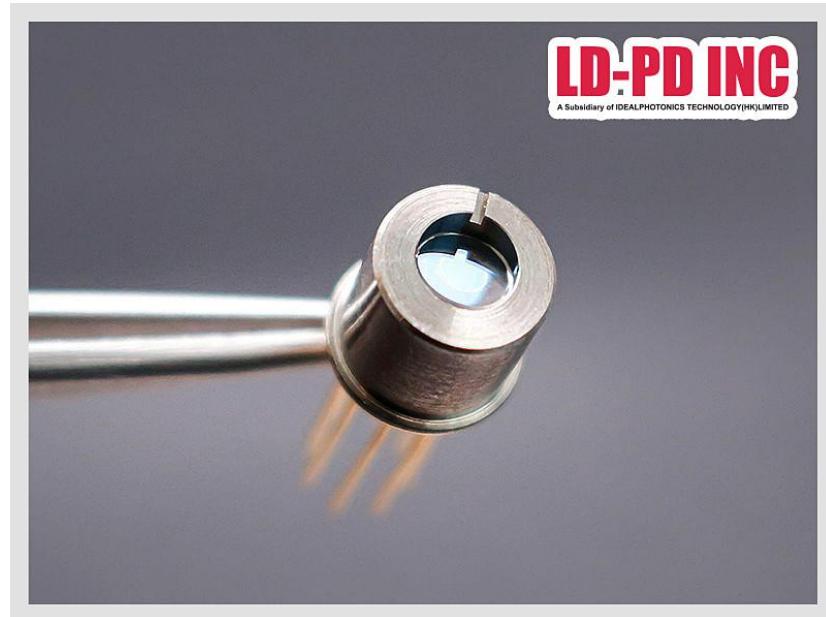


## 1653.7nm DFB Laser diode for CH<sub>4</sub> Sensing (TO39 Package)



### Description

The PL-DFB-1653.7-A1 1653.7nm DFB laser diode module made by LD-PD is a cost effective, highly coherent laser source. The DFB laser diode chip is packaged in an industry standard hermetically sealed TO39 package with TEC and PD Built in.

### Features

- Narrow Linewidth < 2MHz
- Excellent wavelength control and stability
- Industry Standard 14 pin Butterfly package
- Mode-Hop free tuning
- Excellant reliability
- Customer specific wavelengths available

### Application

- Tunable diode laser absorption spectroscopy
- CH<sub>4</sub> Monitoring

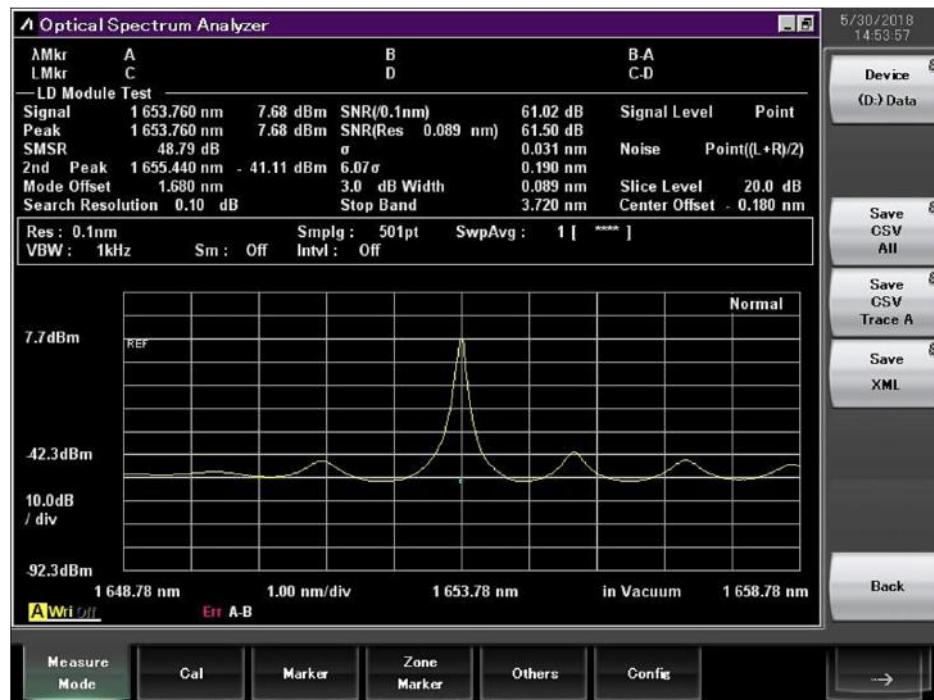
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## Laser Specifications

Electrical/Optical Characteristics(T<sub>sub</sub>=25°C, CW bias unless stated otherwise)

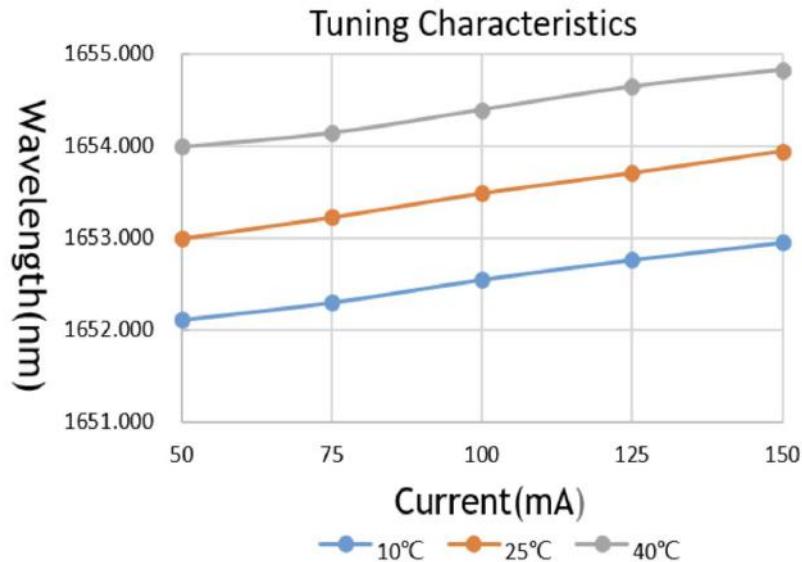
Parameter	Symbol	Min	Typ	Max	Unit
Centre Wavelength	$\lambda$	1653.2	1653.7	1654.2	nm
Side Mode Suppression Ratio	SMSR	30	40		dB
Threshold Current	I <sub>th</sub>		20	30	mA
Operating Current	I <sub>op</sub>		80	120	mA
Chip output Power	P <sub>f</sub>	3	5	10	mW
Quantum Efficiency	$\eta$	0.08	0.12		mW/mA
Current Tuning Coefficient	$\Delta\lambda/\Delta I$		0.015		nm/mA
Temperature Tuning Coefficient	$\Delta\lambda/\Delta T$		0.12		nm/K
Forward Voltage	V <sub>f</sub>		1.3	2	V
Thermistor Resistance	R <sub>T</sub>	9.5	10	10.5	KΩ
Thermistor Temp. Coefficient			-4.4		%/°C
Collimation Lense	Yes				

## Spectrum

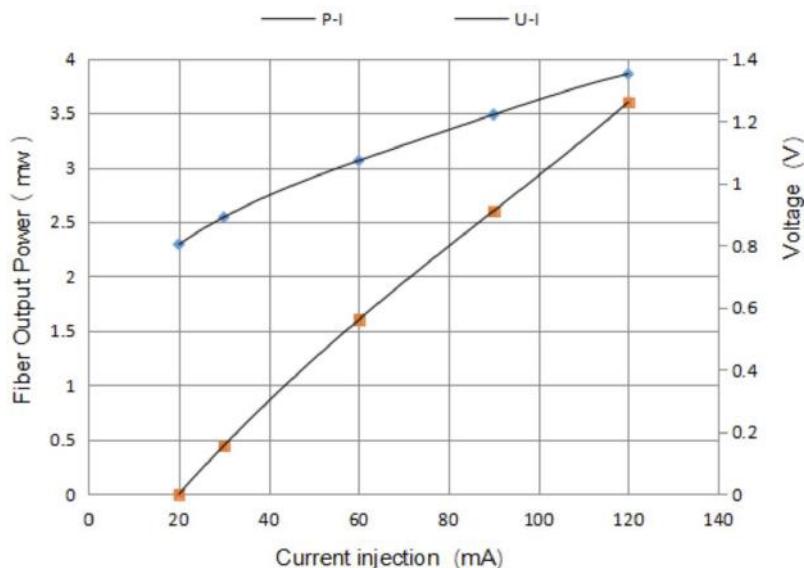


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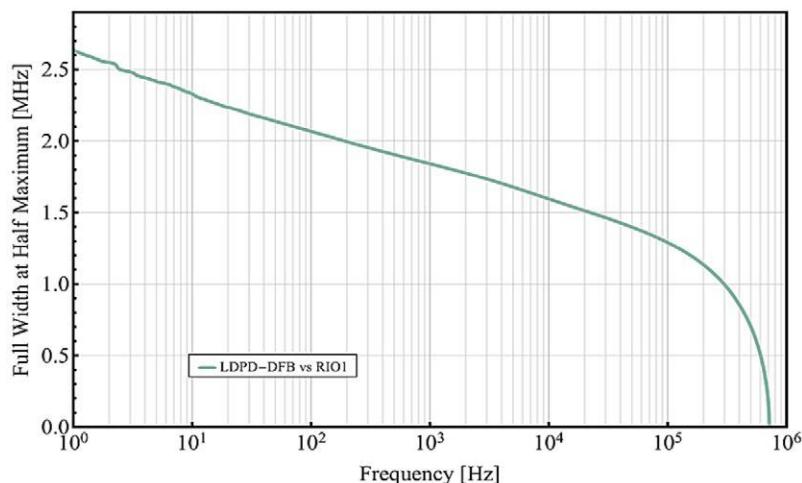
## Tuning Characteristics



## L-I Curve

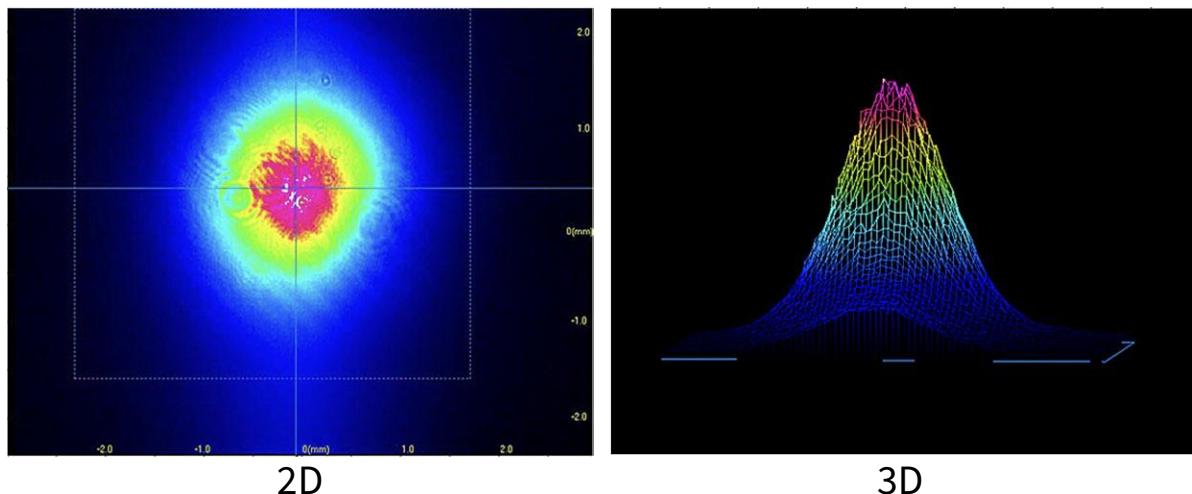


## DFB Linewidth Testing Result

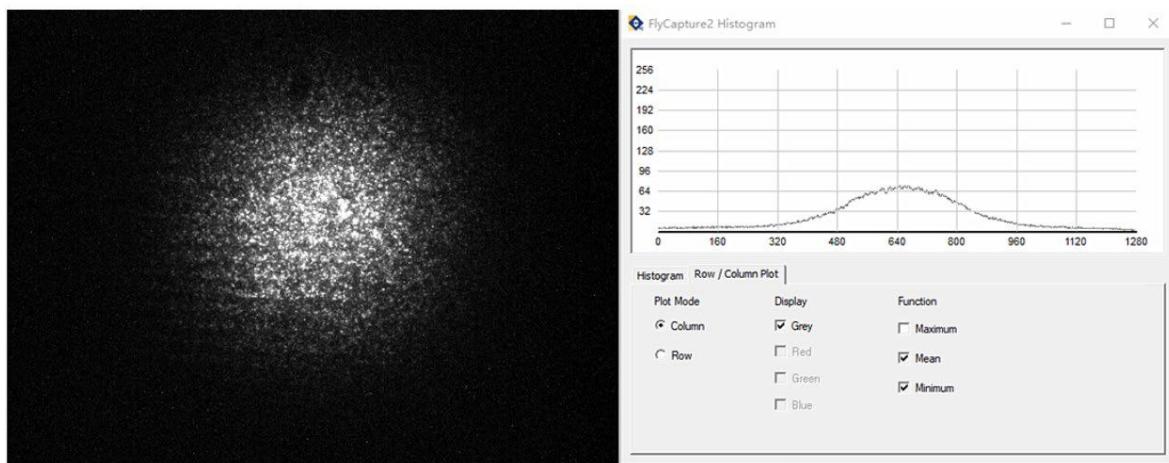


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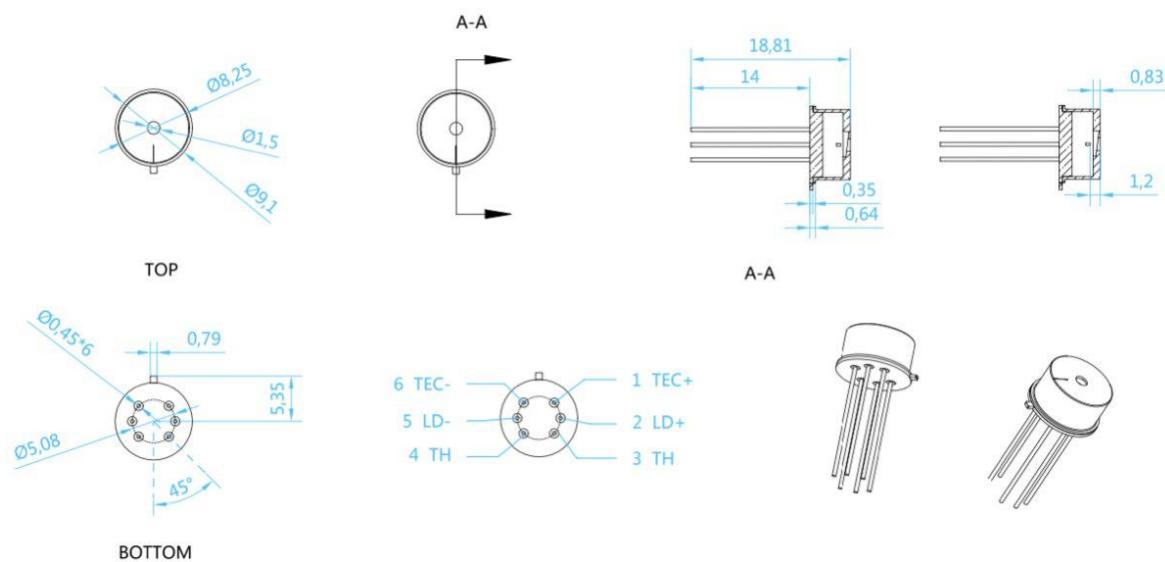
## Beam Quality



## Camera Analysis



## Dimensions and Pin definitions

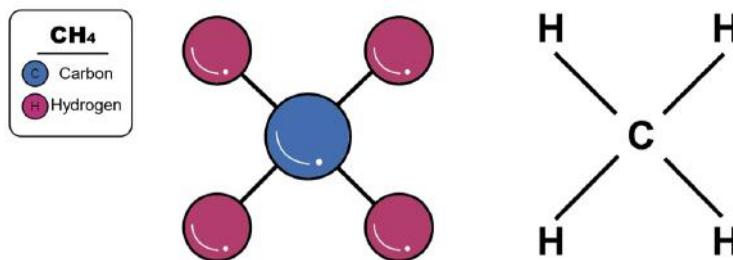
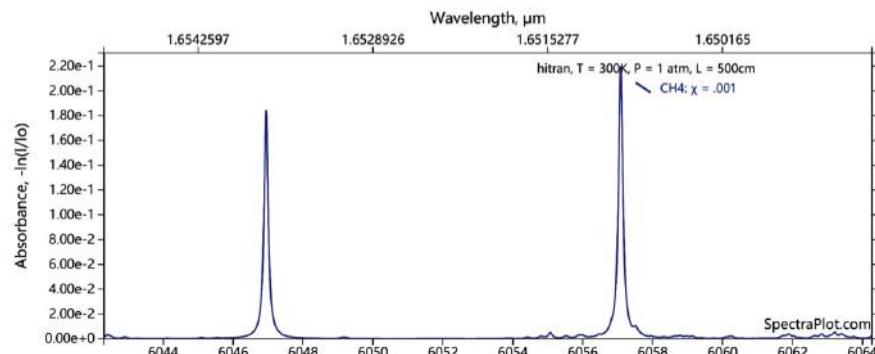


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## Absolute Maximum Ratings

Item	Unit	Min	Typ	Max
Case Temperature	°C	-5	25	70
Chip Temperature	°C	+10	25	40
Operating Current	mA	0	100	120
Forward Voltage	V	0.8	1.2	1.8
TEC Current	A	-	-	1.2
Reverse Voltage (LD)	V	-	-	2.0
Reverse Voltage(PD)	V	-	-	20

## CH<sub>4</sub>

**TDLAS: 1650.9nm 1653.7nm**

## OEM Info

**PL-DFB-□□□□-☆-A8▽-TO39**

□□□□:Wavelength

1512:1512nm

\*\*\*\*\*

1653.7:1653.7nm

☆:Output Power

A:5mW ; B:10mW

▽:Wavelength Tolerance

1:±1nm ; 2:±2nm

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